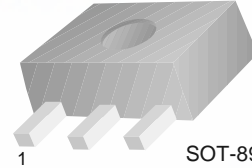


FAIRCHILD
SEMICONDUCTOR®

KSA1203

Low Frequency Power Amplifier

- 3W Output application
- Collector Power Dissipation $P_C=1\sim 2W$: Mounted on Ceramic Board
- Complement to KSC2883



1. Base 2. Collector 3. Emitter

PNP Epitaxial Silicon Transistor

Absolute Maximum Ratings $T_a=25^\circ C$ unless otherwise noted

| Symbol | Parameter | Ratings | Units |
|-----------|-----------------------------|-----------|------------|
| V_{CBO} | Collector-Base Voltage | -30 | V |
| V_{CEO} | Collector-Emitter Voltage | -30 | V |
| V_{EBO} | Emitter-Base Voltage | -5 | V |
| I_C | Collector Current | -1.5 | A |
| I_B | Base Current | -0.3 | A |
| P_C | Collector Power Dissipation | 500 | mW |
| P_C^* | | 1,000 | mW |
| T_J | Junction Temperature | 150 | $^\circ C$ |
| T_{STG} | Storage Temperature | -55 ~ 150 | $^\circ C$ |

* Mounted on Ceramic Board (250mm \times 0.8mm)

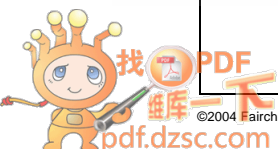
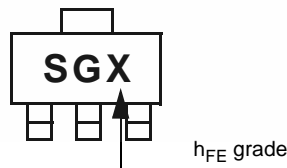
Electrical Characteristics $T_a=25^\circ C$ unless otherwise noted

| Symbol | Parameter | Test Condition | Min. | Typ. | Max. | Units |
|---------------|--------------------------------------|------------------------------------|------|------|------|-------|
| BV_{CEO} | Collector-Emitter Breakdown Voltage | $I_C = -10mA, I_B = 0$ | -30 | | | V |
| BV_{EBO} | Emitter-Base Breakdown Voltage | $I_E = -1mA, I_C = 0$ | -5 | | | V |
| I_{CBO} | Collector Cut-off Current | $V_{CB} = -30V, I_E = 0$ | | | -100 | nA |
| I_{EBO} | Emitter Cut-off Current | $V_{BE} = -5V, I_C = 0$ | | | -100 | nA |
| h_{FE} | DC Current Gain | $V_{CE} = -2V, I_C = -500mA$ | 100 | | 320 | |
| $V_{CE(sat)}$ | Collector-Emitter Saturation Voltage | $I_C = -1.5A, I_B = -30mA$ | | | -2.0 | V |
| $V_{BE(on)}$ | Base-Emitter On Voltage | $V_{CE} = -2V, I_C = -500mA$ | | | -1.0 | V |
| f_T | Current Gain Bandwidth Product | $V_{CE} = -2V, I_C = -500mA$ | | 120 | | MHz |
| C_{ob} | Output Capacitance | $V_{CB} = -10V, I_E = 0, f = 1MHz$ | | | 50 | pF |

h_{FE} Classification

| Classification | O | Y |
|----------------|-----------|-----------|
| h_{FE} | 100 ~ 200 | 160 ~ 320 |

Marking



Typical Characteristics

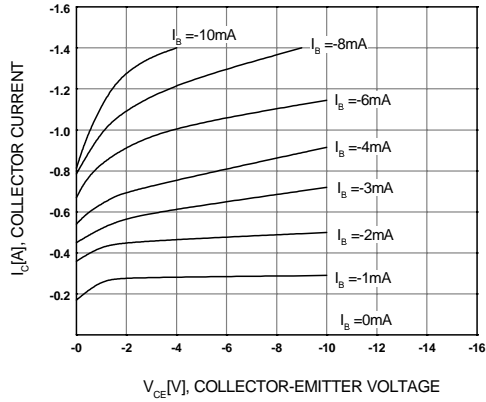


Figure 1. Static Characteristic

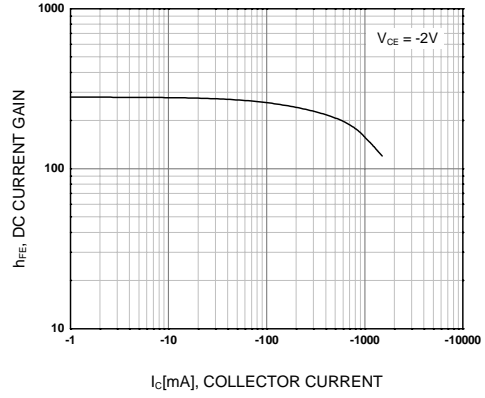


Figure 2. DC current Gain

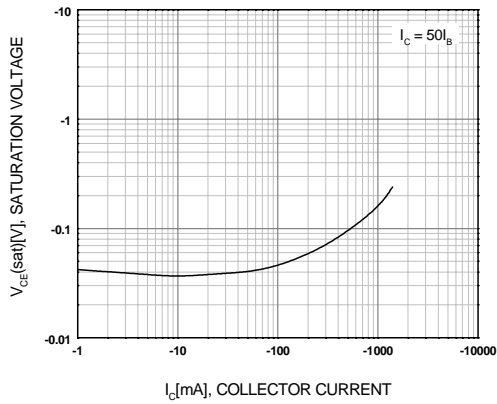


Figure 3. Collector-Emitter Saturation Voltage

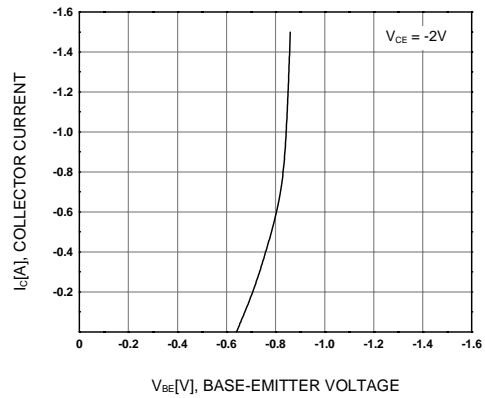


Figure 4. Base-Emitter On Voltage

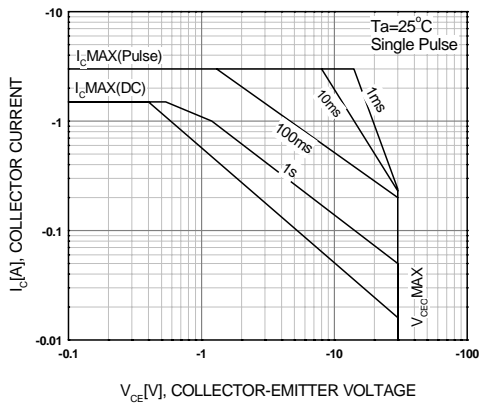


Figure 5. Safe Operating Area

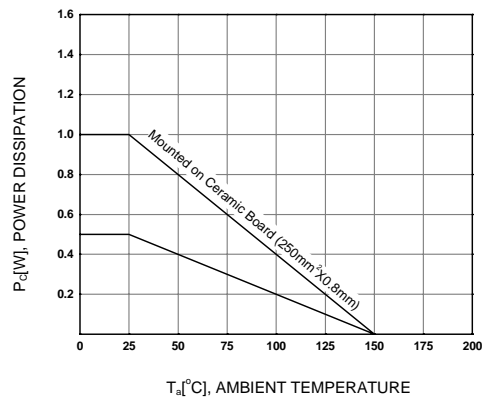
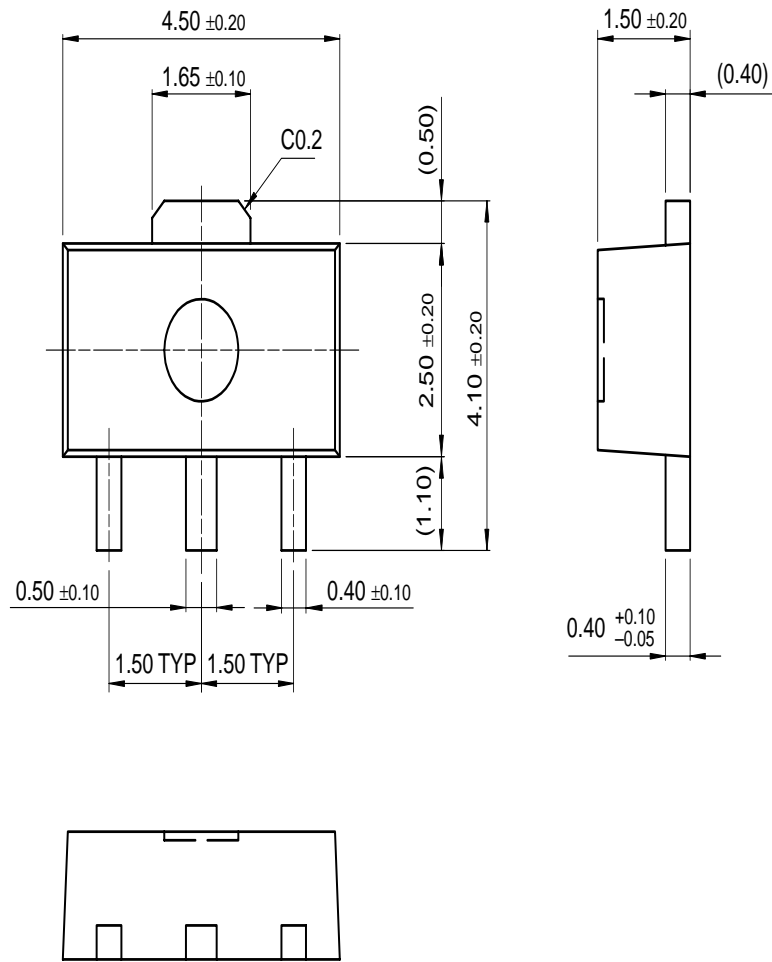


Figure 6. Power Derating

Package Dimensions

SOT-89



Dimensions in Millimeters

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